## FEATURES

## Qualified for automotive applications

Latch-up proof
8 kV human body model (HBM) ESD rating
Low on resistance ( $<10 \Omega$ )
$\pm 9 \mathrm{~V}$ to $\pm \mathbf{2 2} \mathrm{V}$ dual-supply operation
9 V to $\mathbf{4 0} \mathrm{V}$ single-supply operation
48 V supply maximum ratings
Fully specified at $\pm 15 \mathrm{~V}, \pm 20 \mathrm{~V},+12 \mathrm{~V}$, and +36 V
$V_{s s}$ to $V_{D D}$ analog signal range

## APPLICATIONS

## Relay replacement

Automatic test equipment
Data acquisition
Instrumentation

## Avionics

Audio and video switching

## Communication systems

## GENERAL DESCRIPTION

The ADG5412W contains four independent single-pole/singlethrow (SPST) switches. The ADG5412W switches turn on with Logic 1. Each switch conducts equally well in both directions when on, and each switch has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked.
The ADG5412W does not have a $V_{L}$ pin. The digital inputs are compatible with 3 V logic inputs over the full operating supply range.

The on-resistance profile is very flat over the full analog input range, which ensures good linearity and low distortion when switching audio signals. High switching speed also makes the devices suitable for video signal switching.

FUNCTIONAL BLOCK DIAGRAM


NOTES 1. SWITCHES SHOWN FOR A LOGIC 1 INPUT.

Figure 1.

## PRODUCT HIGHLIGHTS

1. Trench isolation guards against latch-up. A dielectric trench separates the P and N channel transistors thereby preventing latch-up even under severe overvoltage conditions.
2. Low Ron.
3. Dual-supply operation. For applications where the analog signal is bipolar, the ADG5412W can be operated from dual supplies up to $\pm 22 \mathrm{~V}$.
4. Single-supply operation. For applications where the analog signal is unipolar, the ADG5412W can be operated from a single rail power supply up to 40 V .
5. 3 V logic compatible digital inputs: $\mathrm{V}_{\mathrm{INH}}=2.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{INL}}=0.8 \mathrm{~V}$.
6. No $\mathrm{V}_{\mathrm{L}}$ logic power supply required.

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REVISION HISTORY
3/14—Rev. 0 to Rev. A
Added TSSOP (RU-16) Model
$\qquad$ Universal

## 12/13-Revision 0: Initial Version

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## SPECIFICATIONS

$\pm 15$ V DUAL SUPPLY
$\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-15 \mathrm{~V} \pm 10 \%, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$, unless otherwise noted.
Table 1.

| Parameter | Min | $\begin{aligned} & \text { Typ } \\ & \left(T_{A}=25^{\circ} \mathrm{C}\right) \end{aligned}$ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | $\mathrm{V}_{\text {dD }}$ to $\mathrm{V}_{\text {SS }}$ | V |  |
| On Resistance, Ron |  | 9.8 | 16 | $\Omega$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+13.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-13.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA} ; \end{aligned}$ $\text { see Figure } 24$ |
| On-Resistance Match Between Channels, $\Delta$ Ron |  | 0.35 | 1.1 | $\Omega$ | $\mathrm{V}_{\mathrm{s}}= \pm 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
| On-Resistance Flatness, Rflat (on) |  | 1.2 | 2.2 | $\Omega$ | $\mathrm{V}_{\mathrm{s}}= \pm 10 \mathrm{~V}, \mathrm{I}_{s}=-10 \mathrm{~mA}$ |
| LEAKAGE CURRENTS |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{S S}=-16.5 \mathrm{~V}$ |
| Source Off Leakage, Is (Off) |  | $\pm 0.05$ | $\pm 10$ | nA | $\mathrm{V}_{\mathrm{s}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 10 \mathrm{~V}$ <br> see Figure 27 |
| Drain Off Leakage, $\mathrm{I}_{\text {( }}$ (Off) |  | $\pm 0.05$ | $\pm 10$ | nA | $\mathrm{V}_{\mathrm{S}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=\mp 10 \mathrm{~V}$ <br> see Figure 27 |
| Channel On Leakage, ID (On), Is (On) |  | $\pm 0.1$ | $\pm 20$ | nA | $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}= \pm 10 \mathrm{~V}$; see Figure 23 |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, $\mathrm{V}_{\text {INH }}$ | 2.0 |  |  | V |  |
| Input Low Voltage, $\mathrm{V}_{\text {INL }}$ |  |  | 0.8 | V |  |
| Input Current, $\mathrm{I}_{\text {INL }}$ or $\mathrm{I}_{\text {INH }}$ |  | 0.002 | $\pm 0.1$ | $\mu \mathrm{A}$ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
| Digital Input Capacitance, $\mathrm{C}_{\text {IN }}$ |  | 2.5 |  | pF |  |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ |  |  |  |  |  |
| ton |  | 170 | 262 | ns | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=10 \mathrm{~V} \text {; see Figure 30, } \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \end{aligned}$ |
| $t_{\text {off }}$ |  | 120 | 182 | ns | $\begin{aligned} & V_{S}=10 \mathrm{~V} \text {; see Figure 30, } \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, C_{L}=35 \mathrm{pF} \end{aligned}$ |
| Charge Injection, QiN |  | 240 |  | pC | $\mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF} ;$ <br> see Figure 31 |
| Off Isolation |  | -78 |  | dB | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; } \\ & \text { see Figure } 26 \end{aligned}$ |
| Channel-to-Channel Crosstalk |  | -70 |  | dB | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \\ & \text { see Figure } 25 \end{aligned}$ |
| Total Harmonic Distortion + Noise |  | 0.009 |  | \% | $R_{L}=1 \mathrm{k} \Omega, 15 \mathrm{Vp}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz}$ <br> to 20 kHz ; see Figure 28 |
| -3 dB Bandwidth |  | 167 |  | MHz | $R_{L}=50 \Omega, C_{L}=5 \mathrm{pF} \text {; see }$ <br> Figure 29 |
| Insertion Loss |  | -0.7 |  | dB | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \\ & \text { see Figure } 29 \end{aligned}$ |
| $\mathrm{C}_{s}$ (Off) |  | 18 |  | pF | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $C_{\text {d }}$ (Off) |  | 18 |  | pF | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{\text {S }}(\mathrm{On})$ |  | 60 |  | pF | $\mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-16.5 \mathrm{~V}$ |
| ldo |  | 45 | 70 | $\mu \mathrm{A}$ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
| Iss |  | 0.001 | 1 | $\mu \mathrm{A}$ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
| $\mathrm{V}_{\mathrm{DD}} / V_{\text {SS }}$ | $\pm 9$ |  | $\pm 22$ | V | GND $=0 \mathrm{~V}$ |

[^0]
## 土20 V DUAL SUPPLY

$\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-20 \mathrm{~V} \pm 10 \%, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$, unless otherwise noted.
Table 2.

| Parameter | Min | Typ <br> $\left(T_{A}=25^{\circ} \mathrm{C}\right)$ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- |

[^1]
## Data Sheet

## 12 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$, unless otherwise noted.
Table 3.

| Parameter | Min | $\begin{aligned} & \text { Typ } \\ & \left(T_{A}=25^{\circ} \mathrm{C}\right) \end{aligned}$ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | 0 V to $\mathrm{V}_{\mathrm{DD}}$ | V |  |
| On Resistance, Ron |  | 19 | 31 | $\Omega$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10.8 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V} \text { to } 10 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA} ; \\ & \text { see Figure } 24 \end{aligned}$ |
| On-Resistance Match Between Channels, $\Delta$ Ron |  | 0.4 | 1.2 | $\Omega$ | $\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
| On-Resistance Flatness, Rflat (on) |  | 4.4 | 7.5 | $\Omega$ | $\mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}$ to $10 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=-10 \mathrm{~mA}$ |
| LEAKAGE CURRENTS |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=13.2 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ |
| Source Off Leakage, Is (Off) |  | $\pm 0.05$ | $\pm 10$ | nA | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=1 \mathrm{~V} / 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=10 \mathrm{~V} / 1 \mathrm{~V} \text {; } \\ & \text { see Figure } 27 \end{aligned}$ |
| Drain Off Leakage, $\mathrm{I}_{\mathrm{D}}$ (Off) |  | $\pm 0.05$ | $\pm 10$ | nA | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=1 \mathrm{~V} / 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=10 \mathrm{~V} / 1 \mathrm{~V} ; \\ & \text { see Figure } 27 \end{aligned}$ |
| Channel On Leakage, Id (On), Is (On) |  | $\pm 0.1$ | $\pm 20$ | nA | $V_{S}=V_{D}=1 \mathrm{~V} / 10 \mathrm{~V} \text {; see }$ <br> Figure 23 |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, $\mathrm{V}_{\text {INH }}$ | 2.0 |  |  | V |  |
| Input Low Voltage, VINL |  |  | 0.8 | V |  |
| Input Current, IINL or ${ }_{\text {linh }}$ |  | 0.002 |  | $\mu \mathrm{A}$ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {GND }}$ or $\mathrm{V}_{\text {DD }}$ |
|  |  |  | $\pm 0.1$ | $\mu \mathrm{A}$ |  |
| Digital Input Capacitance, $\mathrm{C}_{\text {IN }}$ |  | 2.5 |  | pF |  |
| DYNAMIC CHARACTERISTICS ${ }^{1}$ |  |  |  |  |  |
| ton |  | 225 | 403 | ns | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=8 \mathrm{~V} \text {; see Figure 30, } \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \end{aligned}$ |
| toff |  | 150 | 247 | ns | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=8 \mathrm{~V} \text {; see Figure 30, } \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \end{aligned}$ |
| Charge Injection, Qin |  | 95 |  | pC | $\mathrm{V}_{\mathrm{S}}=6 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF} ;$ <br> see Figure 31 |
| Off Isolation |  | -78 |  | dB | $\begin{aligned} & \mathrm{RL}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \\ & \text { see Figure } 26 \end{aligned}$ |
| Channel-to-Channel Crosstalk |  | -70 |  | dB | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \text {; } \\ & \text { see Figure } 25 \end{aligned}$ |
| Total Harmonic Distortion + Noise |  | 0.07 |  | \% | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, 6 \mathrm{~V} \mathrm{p}-\mathrm{p}, \mathrm{f}=20 \mathrm{~Hz}$ <br> to 20 kHz ; see Figure 28 |
| -3 dB Bandwidth |  | 180 |  | MHz | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF} \text {; see }$ <br> Figure 29 |
| Insertion Loss |  | -1.3 |  | dB | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz} \\ & \text { see Figure } 29 \end{aligned}$ |
| $\mathrm{C}_{s}$ (Off) |  | 22 |  | pF | $\mathrm{V}_{\mathrm{S}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $C_{\text {d }}$ (Off) |  | 22 |  | pF | $\mathrm{V}_{\mathrm{s}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| $\mathrm{C}_{\mathrm{D}}(\mathrm{On}), \mathrm{C}_{S}(\mathrm{On})$ |  | 58 |  | pF | $\mathrm{V}_{\mathrm{s}}=6 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| POWER REQUIREMENTS |  |  |  |  | $\mathrm{V}_{\mathrm{DD}}=13.2 \mathrm{~V}$ |
| Iod |  | 40 | 65 | $\mu \mathrm{A}$ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
| $V_{D D}$ | 9 |  | 40 | V | $\mathrm{GND}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{ss}}=0 \mathrm{~V}$ |

[^2]
## 36 V SINGLE SUPPLY

$\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$, unless otherwise noted.
Table 4.

| Parameter | Min | Typ <br> $\left(T_{A}=25^{\circ} \mathrm{C}\right)$ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- |

[^3]
## Data Sheet

## CONTINUOUS CURRENT PER CHANNEL, Sx OR Dx

Table 5.

| Parameter | $25^{\circ} \mathrm{C}$ | $85^{\circ} \mathrm{C}$ | $125{ }^{\circ} \mathrm{C}$ | Unit |
| :---: | :---: | :---: | :---: | :---: |
| CONTINUOUS CURRENT, Sx OR Dx |  |  |  |  |
| $\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-15 \mathrm{~V}$ |  |  |  |  |
| TSSOP ( $\theta_{\mathrm{JA}}=112.6^{\circ} \mathrm{C} / \mathrm{W}$ ) | 89 | 59 | 37 | mA maximum |
| LFCSP ( $\theta_{\mathrm{JA}}=30.4^{\circ} \mathrm{C} / \mathrm{W}$ ) | 160 | 94 | 49 | mA maximum |
| $\mathrm{V}_{\mathrm{DD}}=+20 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-20 \mathrm{~V}$ |  |  |  |  |
| TSSOP ( $\theta_{\text {JA }}=112.6^{\circ} \mathrm{C} / \mathrm{W}$ ) | 95 | 63 | 39 | mA maximum |
| LFCSP ( $\theta_{\mathrm{JA}}=30.4{ }^{\circ} \mathrm{C} / \mathrm{W}$ ) | 170 | 98 | 50 | mA maximum |
| $\mathrm{V}_{\text {DD }}=12 \mathrm{~V}, \mathrm{~V}_{S S}=0 \mathrm{~V}$ |  |  |  |  |
| TSSOP ( $\theta_{\mathrm{JA}}=112.6^{\circ} \mathrm{C} / \mathrm{W}$ ) | 61 | 43 | 29 | mA maximum |
| LFCSP ( $\theta_{\mathrm{JA}}=30.4^{\circ} \mathrm{C} / \mathrm{W}$ ) | 110 | 70 | 42 | mA maximum |
| $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=0 \mathrm{~V}$ |  |  |  |  |
| TSSOP ( $\theta_{\mathrm{JA}}=112.6^{\circ} \mathrm{C} / \mathrm{W}$ ) | 80 | 54 | 35 | mA maximum |
| LFCSP ( $\theta_{\mathrm{JA}}=30.4^{\circ} \mathrm{C} / \mathrm{W}$ ) | 144 | 87 | 47 | mA maximum |

## ABSOLUTE MAXIMUM RATINGS

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.
Table 6.

| Parameter | Rating |
| :---: | :---: |
| $V_{\text {DD }}$ to V $\mathrm{V}_{\text {S }}$ | 48 V |
| Vod to GND | -0.3 V to +48 V |
| $\mathrm{V}_{\text {ss }}$ to GND | +0.3 V to -48 V |
| Analog Inputs ${ }^{1}$ | $\mathrm{V}_{\mathrm{SS}}-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V} \text { or }$ 30 mA , whichever occurs first |
| Digital Inputs ${ }^{1}$ | $V_{S S}-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V} \text { or }$ 30 mA , whichever occurs first |
| Peak Current, Sx or Dx Pins | 278 mA (pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle maximum) |
| Continuous Current, Sx or Dx ${ }^{2}$ | Data + 15\% |
| Temperature Range |  |
| Operating | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Thermal Impedance, $\theta_{\mathrm{JA}}$ |  |
| 16-Lead TSSOP (4-Layer Board) | $112.6^{\circ} \mathrm{C} / \mathrm{W}$ |
| 16-Lead LFCSP (4-Layer Board) | $30.4{ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Reflow Soldering Peak Temperature, Pb Free | As per JEDEC J-STD-020 |

[^4]Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
Only one absolute maximum rating can be applied at any one time.

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. <br> Charged devices and circuit boards can discharge <br> without detection. Although this product features <br> patented or proprietary protection circuitry, damage <br> may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to <br> avoid performance degradation or loss of functionality. |
| :--- | :--- |

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Figure 2. TSSOP Pin Configuration


Figure 3. LFCSP Pin Configuration

Table 7. Pin Function Descriptions

| Pin No. |  |  |  |
| :--- | :--- | :--- | :--- |
| TSSOP | LFCSP | Mnemonic | Description |
| 1 | 15 | IN1 | Logic Control Input 1. |
| 2 | 16 | D1 | Drain Terminal 1. This pin can be an input or output. |
| 3 | 1 | S1 | Source Terminal 1. This pin can be an input or output. |
| 4 | 2 | VSS | Most Negative Power Supply Potential. |
| 5 | 3 | GND | Ground (0 V) Reference. |
| 6 | 4 | S4 | Source Terminal 4. This pin can be an input or output. |
| 7 | 5 | D4 | Drain Terminal 4. This pin can be an input or output. |
| 8 | 6 | IN4 | Logic Control Input 4. |
| 9 | 7 | IN3 | Logic Control Input 3. |
| 10 | 8 | D3 | Drain Terminal 3. This pin can be an input or output. |
| 11 | 9 | S3 | Source Terminal 3. This pin can be an input or output. |
| 12 | 10 | NC | No Connection. |
| 13 | 11 | VDD | Most Positive Power Supply Potential. |
| 14 | 12 | S2 | Source Terminal 2. This pin can be an input or output. |
| 15 | 13 | D2 | Drain Terminal 2. This pin can be an input or output. |
| 16 | 14 | IN2 | Logic Control Input 2. |
|  | EP | Exposed Pad | The exposed pad is connected internally. For increased reliability of the solder joints |
|  |  |  | and maximum thermal capability, it is recommended that the pad be soldered to the |
|  |  |  |  |

Table 8. ADG5412W Truth Table

| INx | Switch Condition |
| :--- | :--- |
| 1 | On |
| 0 | Off |

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 4. RoN as a Function of $V_{S}, V_{D}$ (Dual Supply)


Figure 5. RoN as a Function of $V_{S}, V_{D}$ (Dual Supply)


Figure 6. Ron as a Function of $V_{S}, V_{D}$ (Single Supply)


Figure 7. Ron as a Function of $V_{S}, V_{D}$ (Single Supply)


Figure 8. Ron as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, $\pm 15$ V Dual Supply


Figure 9. RoN as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, $\pm 20$ V Dual Supply


Figure 10. Ron as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, 12 V Single Supply


Figure 11. Ron as a Function of $V_{S}\left(V_{D}\right)$ for Different Temperatures, 36 V Single Supply


Figure 12. Leakage Currents vs. Temperature, $\pm 15$ V Dual Supply


Figure 13. Leakage Currents vs. Temperature, $\pm 20$ V Dual Supply


Figure 14. Leakage Currents vs. Temperature, 12 V Single Supply


Figure 15. Leakage Currents vs. Temperature, 36 V Single Supply


Figure 16. Off Isolation vs. Frequency, $\pm 15$ V Dual Supply


Figure 17. Crosstalk vs. Frequency, $\pm 15$ V Dual Supply


Figure 18. Charge Injection vs. Source Voltage


Figure 19. ACPSRR vs. Frequency, $\pm 15$ V Dual Supply


Figure 20. $T H D+N$ vs. Frequency, $\pm 15$ V Dual Supply


Figure 21. Bandwidth


Figure 22. ton, $t_{\text {off }}$ Times vs. Temperature

## TEST CIRCUITS



Figure 23. On Leakage


Figure 27. Off Leakage


Figure 28. THD + Noise


Figure 29. Bandwidth


Figure 26. Off Isolation


Figure 31. Charge Injection

## TERMINOLOGY

$\mathrm{I}_{\mathrm{DD}}$
$\mathrm{I}_{\mathrm{DD}}$ represents the positive supply current.
Iss
Iss $_{\text {s }}$ represents the negative supply current.
$V_{D}, V_{s}$
$\mathrm{V}_{\mathrm{D}}$ and $\mathrm{V}_{\mathrm{S}}$ represent the analog voltage on Terminal D and Terminal S, respectively.
Ron
Ron represents the ohmic resistance between Terminal D and Terminal S.

## $\Delta$ Ron

$\Delta$ Ron represents the difference between the Ron of any two channels.
$\mathbf{R}_{\text {flat (ON) }}$
Flatness that is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range is represented by $\mathrm{R}_{\text {FLAT (ON) }}$.

Is (Off)
Is (Off) is the source leakage current with the switch off.
$\mathrm{I}_{\mathrm{D}}$ (Off)
$\mathrm{I}_{\mathrm{D}}$ (Off) is the drain leakage current with the switch off.
$\mathrm{I}_{\mathrm{D}}(\mathrm{On}), \mathrm{I}_{\mathrm{s}}(\mathrm{On})$
$\mathrm{I}_{\mathrm{D}}(\mathrm{On})$ and $\mathrm{I}_{\mathrm{S}}(\mathrm{On})$ represent the channel leakage currents with the switch on.
$V_{\text {INL }}$
$\mathrm{V}_{\text {INL }}$ is the maximum input voltage for Logic 0 .
$V_{\text {INH }}$
$\mathrm{V}_{\text {INH }}$ is the minimum input voltage for Logic 1.
$\mathrm{I}_{\mathrm{INL}}, \mathrm{I}_{\mathrm{INH}}$
$\mathrm{I}_{\text {INL }}$ and $\mathrm{I}_{\text {INH }}$ represent the low and high input currents of the digital inputs.
$\mathrm{C}_{\mathrm{D}}$ (Off)
$C_{D}$ (Off) represents the off switch drain capacitance, which is measured with reference to ground.
$\mathrm{C}_{\mathrm{s}}$ (Off)
$\mathrm{C}_{S}$ (Off) represents the off switch source capacitance, which is measured with reference to ground.
$\mathrm{C}_{\mathrm{D}}$ (On), $\mathrm{C}_{\mathrm{s}}$ (On)
$C_{D}(\mathrm{On})$ and $\mathrm{C}_{s}(\mathrm{On})$ represent on switch capacitances, which are measured with reference to ground.

## $\mathrm{C}_{\text {IN }}$

$\mathrm{C}_{\text {IN }}$ is the digital input capacitance.
ton
$t_{\text {ON }}$ represents the delay between applying the digital control input and the output switching on.
$\boldsymbol{t}_{\text {OfF }}$
toff represents the delay between applying the digital control input and the output switching off.
to
$t_{D}$ represents the off time measured between the $80 \%$ point of both switches when switching from one address state to another.

## Off Isolation

Off isolation is a measure of unwanted signal coupling through an off switch.

## Charge Injection

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

## Crosstalk

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

## Bandwidth

Bandwidth is the frequency at which the output is attenuated by 3 dB .

## On Response

On response is the frequency response of the on switch.

## Insertion Loss

Insertion loss is the loss due to the on resistance of the switch.
Total Harmonic Distortion + Noise (THD + N)
The ratio of the harmonic amplitude plus noise of the signal to the fundamental is represented by THD + N.

## AC Power Supply Rejection Ratio (ACPSRR)

ACPSRR is the ratio of the amplitude of signal on the output to the amplitude of the modulation. This is a measure of the ability of the part to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p.

## APPLICATIONS INFORMATION

The ADG54xx family of switches and multiplexers provide a robust solution for instrumentation, industrial, automotive, aerospace, and other harsh environments that are prone to latch-up, which is an undesirable high current state that can lead to device failure and persists until the power supply is turned off. The ADG5412W high voltage switches allow singlesupply operation from 9 V to 40 V and dual-supply operation from $\pm 9 \mathrm{~V}$ to $\pm 22 \mathrm{~V}$. The ADG5412W (as well as other select devices within the same family) achieve an 8 kV human body model ESD rating, which provides a robust solution eliminating the need for separate protect circuitry designs in some applications.

## TRENCH ISOLATION

In the ADG5412W, an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction isolated switches, are eliminated, and the result is a completely latch-up proof switch.

In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. A silicon controlled rectifier (SCR) type circuit is formed by the two transistors causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latchup proof switch.


Figure 32. Trench Isolation

## OUTLINE DIMENSIONS



Figure 33. 16-Lead Thin Shrink Small Outline Package [TSSOP] ( $R U-16$ )
Dimensions shown in millimeters


COMPLIANT TO JEDEC STANDARDS MO-220-WGGC.
Figure 34. 16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]
$4 \mathrm{~mm} \times 4 \mathrm{~mm}$ Body, Very Very Thin Quad
(CP-16-17)
Dimensions shown in millimeters

ORDERING GUIDE

| Model $^{1,2}$ | Temperature Range | Package Description | Package Option |
| :--- | :--- | :--- | :--- |
| ADG5412WBRUZ-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG5412WBCPZ-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package [LFCSP_WQ] | CP-16-17 |

${ }^{1} Z=$ RoHS Compliant Part.
${ }^{2}$ W $=$ Qualified for Automotive Applications.

## AUTOMOTIVE PRODUCTS

The ADG5412W models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.
$\square$
Data Sheet
NOTES

# Mouser Electronics 

Authorized Distributor

Click to View Pricing, Inventory, Delivery \& Lifecycle Information:

Analog Devices Inc.:
ADG5412BRUZ-REEL7 ADG5412BRUZ ADG5412WBCPZ-REEL7 ADG5412WBRUZ-REEL7 ADG5412BCPZ-
REEL7 EVAL-16TSSOPEBZ


[^0]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^1]:    ${ }^{1}$ Guaranteed by design; not subject to production test

[^2]:    ${ }^{1}$ Guaranteed by design; not subject to production test.

[^3]:    ${ }^{1}$ Guaranteed by design; not subject to production test

[^4]:    ${ }^{1}$ Overvoltages at the $\mathrm{INx}, \mathrm{Sx}$, and Dx pins are clamped by internal diodes. Limit current to the maximum ratings given.
    ${ }^{2}$ See Table 5.

